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CONFIRMATION NO. 6362

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|--|---|-----------------------------------|---|--|--------------------------------|
| SERIAL NUMBER 10/815,473 | FILING OR 371(c) DATE 04/01/2004 RULE | CLASS 257 | GROUP ART UNIT 2813 | ATTORNEY DOCKET NO. 03-GR1-020 | |
| APPLICANTS Vincent Cosnier, Grenoble, FRANCE; Yves Morand, Grenoble, FRANCE; Olivier Kermarrec, Gieres, FRANCE; Daniel Bensahel, Grenoble, FRANCE; Yves Campidelli, Grenoble, FRANCE; | | | | | |
| ** CONTINUING DATA ***** | | | | | |
| ** FOREIGN APPLICATIONS ***** FRANCE 03 04008 04/01/2003 | | | | | |
| IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 06/17/2004 | | | | | |
| Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after met Verified and Acknowledged <input checked="" type="checkbox"/> Allowance Examiner's Signature <i>[Signature]</i> Initials <i>[Initials]</i> | | STATE OR COUNTRY FRANCE | SHEETS DRAWING 1 | TOTAL CLAIMS 18 | INDEPENDENT CLAIMS 2 |
| ADDRESS 23334 | | | | | |
| TITLE Method of fabricating a semiconductor device comprising a gate dielectric made of high dielectric permittivity material | | | | | |
| FILING FEE RECEIVED 900 | FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following: | | <input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit | | |